Grain boundary complexions and pseudopartial wetting

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1. Introduction

The developments of last decade show that properties of fine-grained and nanograined materials are critically controlled by the behaviour of grain boundaries (GBs) and triple junctions (TJs) [1–4]. Moreover, the most advanced experimental methods like high-resolution electron microscopy (HREM) and atom probe microscopy allowed observing that GBs and TJs are frequently not atomically thin and smooth but contain the few nm thick layers or so-called intergranular films (IGFs) [3–21]. Such IGFs form the important class of grain boundary complexions [5,6,21] having composition which strongly differs from that of the abutting grains. These layers can appear in equilibrium, non-equilibrium (transient) or steady-state structures [4–20,22–31]. In the majority of cases such surface and GB complexions are intimately connected with GB wetting, prewetting and premelting equilibrium complex transitions in the bulk phase diagrams. In the majority of systems, the direct transition between complete and partial GB wetting takes place (by changing temperature, pressure, etc.). However, in certain conditions the so-called pseudopartial (or pseudo incomplete, or frustrated complete) GB wetting appears in a phase diagram between complete and partial wetting. In case of pseudopartial GB wetting, the thin GB layer of a complexion (IGF or 2-D interfacial phase) can coexist with large droplets (or particles) of the wetting phase with a non-zero dihedral (contact) angle. Thus, such IGFs can be observed in the two-phase (or multiphase) fields of bulk phase diagrams, in the broad intervals of concentrations, temperature and/or pressure. The IGFs driven by the pseudopartial GB wetting can drastically modify the properties of polycrystals. In this review, we discuss this phenomenon for the technologically important Fe–Nd–B-based hard magnetic alloys, WC–Co cemented carbides and Al-based light alloys.

1.1. Complex grain boundary wetting

Grain boundary complexions include the few nanometer thick layers having composition which strongly differs from that of the abutting grains. Such GB complexions are frequently called intergranular films (IGFs) and can be observed close to the lines of wetting, prewetting and premelting complexion transitions in the bulk phase diagrams. In the majority of systems, the direct transition between complete and partial GB wetting takes place (by changing temperature, pressure, etc.). However, in certain conditions the so-called pseudopartial (or pseudo incomplete, or frustrated complete) GB wetting appears in a phase diagram between complete and partial wetting. In case of pseudopartial GB wetting, the thin GB layer of a complexion (IGF or 2-D interfacial phase) can coexist with large droplets (or particles) of the wetting phase with a non-zero dihedral (contact) angle. Thus, such IGFs can be observed in the two-phase (or multiphase) fields of bulk phase diagrams, in the broad intervals of concentrations, temperature and/or pressure. The IGFs driven by the pseudopartial GB wetting can drastically modify the properties of polycrystals. In this review, we discuss this phenomenon for the technologically important Fe–Nd–B-based hard magnetic alloys, WC–Co cemented carbides and Al-based light alloys.
2. Definition of pseudopartial wetting

The pseudopartial (or pseudoincomplete, or frustrated complete) wetting, where the bulk phase of a fluid has a nonzero contact angle on top of a film of the same fluid, has been of interest in the scientific literature since the end of 1980s [34–40,50–53]. Let us consider a partially melted two- or multicomponent polycrystal between solidus temperature $T_S$ and liquidus temperature $T_L$. Consider the droplet of a liquid phase on the surface of a solid phase or between two solid grains. Usually one distinguishes partial (incomplete) and complete wetting of surfaces or interfaces. In case of complete wetting the contact angle $\theta$ is zero. If the contact angle $\theta$ is between zero and $180^\circ$ one speaks about partial or incomplete wetting [6]. We will use further this terminology though in some literature sources one speaks about partial wetting when the contact angle is between $90^\circ$ and $180^\circ$. In these sources one uses “wetting” (meaning complete or perfect wetting) vs. “non-wetting” (including partial wetting, which is “non-wetting” thermodynamically) [6].

If a liquid droplet partially wets a solid surface (Fig. 1a) then $\sigma_{sg} = \sigma_{sl} \cos \theta$, where $\sigma_{sg}$ is the free energy of solid/gas interface, $\sigma_{sl}$ is the free energy of solid/liquid interface, $\sigma_{lg}$ is that of liquid/gas interface. If a liquid droplet partially wets the boundary between two solid grains (Fig. 1b), then $\sigma_{gb} = 2 \sigma_{sg} \cos \theta$, where $\sigma_{gb}$ is the free energy of a grain boundary. The free surface or GB which is not covered by the droplets remains dry and contains only adsorbed atoms of a second component with coverage below one monolayer. In this case the GB can exist in the equilibrium contact with the liquid phase. If $\sigma_{sg} = \sigma_{sl} \cos \theta$ or $\sigma_{gb} = 2 \sigma_{sl}$ complete wetting of free surface or grain boundary takes place and $\theta$ reaches zero [Fig. 1c and d] [54]. We have to underline here the subtle but important difference between “dry” interfaces and equilibrium interfaces [19,54,55]. In the criteria used above, the terms $\sigma_{sg}$ and $\sigma_{gb}$ actually refer to the so-called “dry” or “clean” surface or GB before wetting (without adsorption of the wetting phase) [19,54,55]. However, the wetted surface or GB is the new interface thermodynamically [54]. In the literature, there are two ways to differentiate this subtle, but important, difference. In the surface wetting community, one frequently use $\sigma_{sg}$ (meaning the solid/vacuum interface) to denote that it is different from the equilibrium $\sigma_{sg}$ (meaning the equilibrium solid/gas interface), which, at equilibrium, will be wetted so that $\sigma_{sg} = \sigma_{sg} + \sigma_{sl}$ [54]). This notation is difficult to be used for denoting “dry” or “clean” GBs, so other authors use symbols like $\sigma_{sg}^0$ [19,55] to differentiate “dry” or “clean” GBs from the equilibrium GBs with equilibrium adsorption, disordering or wetting (here wetting means adsorption with infinite GB excess). Thus, in the case $\sigma_{sg} > \sigma_{sl} + \sigma_{sl}$ or $\sigma_{gb} > 2 \sigma_{sl}$, the contact angle $\theta$ also remains zero, and liquid spreads over the free surface or between grains. In this case, a GB separating abutting grains is completely substituted by the liquid phase.

The transition from incomplete to complete (partial) GB wetting proceeds at a certain $T_w$ if the energy of two solid-liquid interfaces $2 \sigma_{sl}$ becomes lower than the GB energy $\sigma_{gb} > 2 \sigma_{sl}$. Cahn [32] and Ebner and Saam [33] first showed that the (reversible) transition from incomplete to complete wetting can proceed with increasing temperature, and that it is a true surface phase (complexion) transformation. The GB wetting temperatures $T_w$ depend both on GB energy and solid-liquid interfacial energy which, in turn, depend on the crystallography of these interfaces [56–59]. The transition from incomplete to complete GB wetting starts at a certain minimum temperature $T_{wmin}$. $T_{wmin}$ is determined by combination of maximum $\sigma_{gb}$ and minimum $\sigma_{sl}$. The transition from incomplete to complete GB wetting finishes at a maximum temperature $T_{wmax}$. $T_{wmax}$ in turn, is determined by combination of minimum $\sigma_{gb}$ and maximum $\sigma_{sl}$. The fraction of completely wetted GBs increases from 0 to 100% as the temperature increases from $T_{wmin}$ to $T_{wmax}$ [60–65]. As a result, the new tie-lines appear in the $S + L$ area of a phase diagram at $T_{wmin}$ and $T_{wmax}$ [60–65].

In case of complete wetting (Fig. 1c and d), $\sigma_{sg} > \sigma_{sl} + \sigma_{sl}$ or $\sigma_{gb} > 2 \sigma_{sl}$ contact angle $\theta$ is zero, and liquid spreads over the free surface or between grains. What happens, if the amount of liquid is small and surface (or GB) area is large? In this case the liquid spreads until the abutting solid grains or solid and gas begin to interact with each other through the liquid layer. The liquid forms a “pancake” with thickness $e = (A/4\pi S)^{1/2}$, where $S = \sigma_{sg} - \sigma_{sl} - \sigma_{lg}$ is the spreading coefficient on a strictly “dry” solid and $A$ is the Hamaker constant [40,66]. In case of complete wetting, $A > 0$ and $S > 0$ [40,66]. Such “pancake” (complexion) on the free surface or between two grains is formed by the deficit of a wetting phase. Such conditions can be found in the $\alpha + L$ two-phase area of a phase diagram, but in the narrow “temperature (pressure) - concentration” band very close to the solidus line.

In the majority of cases, the direct transition occurs from partial wetting into complete wetting, for example by increasing temperature [59,67,68] or decreasing pressure [69]. However, in some cases, the pseudopartial wetting (PW in Fig. 1g) appears between partial and complete wetting. In this case the contact angle $\theta > 0$, the liquid droplet does not spread over the substrate, but the thin (few nm) precursor film exists around the droplet and separates substrate and gas (Fig. 1e). Such thin precursor film (complexion) is very similar to the liquid “pancake” which forms in case of
complete wetting and deficit of the liquid phase. This case is called pseudopartial wetting, it is possible when $A < 0$ and $S > 0$ [66]. In case of pseudopartial wetting the precursor exists simultaneously with liquid droplets. In case of complete wetting, conversely, the droplets disappear and form a “pancake”.

The sequence of discontinuous PW ↔ PPW and continuous PPW ↔ CW has been observed for the first time in the alcanes/water mixture [70]. The critical end point (CEP in Fig. 1f) was observed in a mixture of pentane and hexane which was deposited on an aqueous solution of glucose [35]. The first direct measurement of the contact angle in the intermediate wetting state (pseudo-partial wetting) was performed in the sequential-wetting scenario of hexane on salt brine [70]. Later the formation of Pb, Bi and binary Pb–Bi precursors surrounding liquid or solidified droplets has been observed on the surface of solid copper [71].

3. Grain boundary IGFs (complexions) and pseudopartial wetting in the Fe–Nd–B-based magnets, WC–Co cemented carbides and Al-based light alloys

3.1. Fe–Nd–B-based permanent magnets

Nd–Fe–B-based alloys for permanent magnets were invented in 1980s. They remain up to now the best known hard magnetic alloys with highest magnetic energy product $BH$ ($B$ being the flux density and $H$ being the field strength). In order to reach the optimum magnetic properties, the Nd$_2$Fe$_{14}$B grains have to be isolated one from another by the layers of a non-ferromagnetic phase. In most cases it is the Nd-rich phase. The Nd-rich phase appears during the liquid-phase sintering as liquid layer between Nd$_2$Fe$_{14}$B grains. It has been demonstrated rather early [43], that the thickness of these layers needed for effective magnetic isolation between Nd$_2$Fe$_{14}$B grains is only few nanometers [44]. Such 2–5 nm thick layers (IGFs or complexions) in Nd$_2$Fe$_{14}$B/Nd$_2$Fe$_{14}$B GBs were recently observed using HREM [72–74]. If the total amount of the Nd-rich phase is too high, it decreases the saturation magnetization of an alloy as a whole. Therefore, the amount of the Nd-rich phase has to be kept as low as possible, namely at the level which is minimally needed for the effective magnetic isolation between grains of the hard magnetic Nd$_2$Fe$_{14}$B phase. It is the reason for the technological interest to the thin GB layers (IGFs or complexions) in the Nd–Fe–B-based alloys.

In [42] the Nd–Fe–B-based liquid-phase sintered alloy was purchased from the company Vacuumschmelze GmbH (Germany), it contained 66.5 wt% Fe, 22.1 wt% Nd, 9.4 wt% Dy, 1.0 wt% Co, 0.8 wt% B, 0.2 wt% Cu. Samples were sealed into evacuated silica ampoules and annealed at 900 °C for 2 h, and then quenched in water. Transmission electron microscopy (TEM, HRTEM, STEM, EDXS) studies were carried out on the TECNAI instrument. X-ray diffraction (XRD) data were obtained on a Siemens diffractometer (Co Kα radiation). TEM lamellas were prepared on the STRATA dual beam facility.

In Fig. 2a the STEM micrograph of a triple joint between three Nd$_2$Fe$_{14}$B grains is shown. Chemical composition of these three grains measured by the EDXS in TEM corresponds to that of Nd$_2$Fe$_{14}$B hard magnetic phase. Triple joint shown in Fig. 2a is filled by the Nd-rich phase. The Nd-rich phase was liquid during the liquid phase sintering and annealing at 900 °C [75–77]. Fig. 2d–f shows the Fe and Nd concentration profiles across all three Nd$_2$Fe$_{14}$B/Nd$_2$Fe$_{14}$B GBs in the locations C, B and A (Fig. 2a), respectively. The first two profiles do not contain any Fe and/or Nd maxima or minima. It means that the respective GBs C and B remain “dry” and are not enriched (depleted) by the Fe and/or Nd. The GBs C and B have the non-zero contact angle with Nd-rich phase in the triple junction. In other words, the GBs C and B are incompletely (partially) wetted by the Nd-rich melt. This situation corresponds to the scheme shown in Fig. 1b.

The GB A is different. The concentration profile in Fig. 2f shows that GB A is enriched by Nd and depleted by Fe. The width of the Nd maximum and Fe minimum in Fig. 2f is about 5 nm. The uniformly thin light-grey layer of a Nd-rich phase is clearly visible also in GB A (Fig. 2a). Fig. 2b shows the conventional TEM micrograph of this GB and Fig. 2c contains the micrograph of the same GB with a thin layer of a Nd-rich phase. Both TEM and HREM also witness that the Nd-rich GB layer is uniformly thin and has a thickness of about 5 nm. The GB A, similar to the GBs C and B, also has the non-zero contact angle with Nd-rich phase in the triple junction. Since GB A is not “dry” and contains the thin Nd-rich layer, this situation corresponds to the scheme shown in Fig. 1f. In other words, the GB C is pseudo-incompletely (or pseudo-partially) wetted by the Nd-rich melt.

Therefore, the boundaries between grains of Nd$_2$Fe$_{14}$B hard magnetic phase in the NdFeB-based permanent magnets can be pseudo-incompletely (or pseudo-partially) wetted by the Nd-rich melt [42]. Such GBs form the non-zero contact angle with the melt in the triple junctions and, simultaneously, contain the uniformly thin (about 5 nm) Nd-rich layer. Therefore, they are different from the completely wetted GBs (zero contact angle and non-uniform and thick Nd-rich layer with thickness above 100 nm), and incompletely wetted GBs (non-zero contact angle, no Nd-rich layer). The thin Nd-rich layers in the pseudo-incompletely (pseudo-partially) wetted Nd$_2$Fe$_{14}$B/Nd$_2$Fe$_{14}$B GBs are most probably responsible for the excellent magnetic properties of the NdFeB-base permanent magnets. It is because these layers can ensure the magnetic isolation between the Nd$_2$Fe$_{14}$B grains needed for the high coercivity.

3.2. WC–Co cemented carbides

WC–Co cemented carbides are metal-ceramic composites consisting of a ceramic phase, namely tungsten carbide, and a cobalt binder. They are broadly used in various industrial applications and almost in each household, for example, as masonry drill bits, due to their unique combination of high hardness, wear-resistance, toughness and strength. Since their discovery in Germany in the 1920s, WC–Co cemented carbides did not dramatically change. The main improvements were related to varying WC grain size, Co content and employing inhibitors of WC grain growth during liquid phase sintering [78,79]. The key to the exceptional properties of cemented carbides is the optimal combination of hardness and wear-resistance of WC grains, and toughness and ductility of the Co-based matrix. Also, the presence of a carbide skeleton of WC grains in the carbide microstructure appears to play a very important role for the unique combination of hardness and fracture toughness of cemented carbides. The skeleton can be designated as the “pseudo-skeleton”, based on the fact that almost all the WC–WC grain boundaries are known to comprise very thin Co interlayers of the order of from nearly one atomic monolayer to several nanometers [45–47]. In this respect, the wetting of boundaries between WC grains by the Co melt during liquid phase sintering is the key issue. It is because pure WC/ WC grain boundaries not comprising the Co interlayers should be quite brittle. It is well known that the wettability of WC by liquid Co examined by the method of a lying droplet is complete, and the wetting angle of a droplet of liquid Co on the surface of WC is equal to 0 at temperatures of 1400–1500 °C [80,81].

Nevertheless, the presence of the “pseudo-skeleton” of WC grains in the cemented carbide microstructure clearly indicates that WC/ WC GBs are characterised by various contact angles with the cobalt-based binder and only very few angles are equal to 0° [39]. Therefore, there is a contradiction between the complete wetting of WC surface by the liquid Co droplets, on the one hand, and...
the contact angles between WC/WC GBs and the Co binder different from 0 in the carbide microstructure, on the other hand. This contradiction was mentioned as early as in 1972 by Warren and Waldron [82]. It can be explained by the pseudopartial GB wetting in cemented carbides and existence of respective GB IGFs or complexions [39].

Ultra-coarse WC-Co cemented carbides were produced according to the procedure described in Ref.[83]. The WC powder (MAS 3000–5000, H.C. Starck) was milled with 10 wt% Co in an attritor-mill for 1 h in hexane with 2 wt% paraffin wax. Samples were pressed and liquid-phase sintered at 1380°C for 75 min (45 min vacuum + 30 min HIP). The cross-sections were then investigated by means of optical microscopy and scanning electron microscopy (SEM). SEM investigations were carried out on a Tescan Vega TS5130 MM microscope equipped with the LINK energy-dispersive spectrometer produced by Oxford Instruments. Transmission electron microscopy (TEM, HRTEM, STEM, EDXS) studies were carried out on the TECNAI microscope.

Histogram indicating the share of WC/WC GBs having a certain contact angle with the Co-based binder shows that there are only very few contact angles equal to 0° (θ = 0°) corresponding to the complete GB wetting [39]. Fig. 3a [39] shows the Z-contrast image obtained by HAADF STEM in the contact area between two WC grains (bright) and the grain of Co-based binder (dark, removed during the preparation of TEM sample). EDS profile of Co concentration across WC/WC GB shown in Fig. 3b demonstrates that this GB contains a thin Co-based layer of nearly 5–7 nm (white line in Fig. 3a). The position of respective line profile is shown in Fig. 3a. The spatial resolution of EDS is about 1–2 nm, the step between points is 1 nm. It means that a gradual composition profile in Fig. 3b is mainly due to the EDS spatial resolution. The contact (dihedral) angle of the WC/WC GB with Co grain (dark, removed during the preparation) is about 90° and, therefore, it is far away from zero. Therefore, the Co-rich thin layer (complexion) in WC/WC GB (Fig. 3b) is a typical example of pseudopartial GB wetting. To our minds, the phenomenon of PPW can explain the special
features of the cemented carbide microstructure and apparent contradiction between the fact of complete wetting of WC surface by a liquid Co droplet and non-zero contact angles between the WC-WC GBs and Co binder.

3.3. Al-based light alloys

In first two cases of Nd–Fe–B-based hard magnetic alloys and WC-Co cemented carbides, the IGFs or complexions were formed in GBs during the liquid phase sintering, i.e. in the contact with liquid phase. In case of the Al–Zn light alloys the liquid phase was absent, and the formation of Zn-rich IGFs or complexions in the Al/Al GBs was ensured by the accelerated mass transfer driven by the so-called severe plastic deformation (SPD). SPD is a family of methods allowing to producing the extremely high strains in a material without its failure (because the material is deformed in a confined space). A very high density of lattice defects appearing during SPD drives various bulk phase transformations in Al/Al GBs completely and partially wetted by the solid Zn phase, i.e. in the contact with liquid phase. In case of Al–Zn alloys SPD (exactly speaking – high pressure torsion, HPT) drives not only bulk phase transition (decomposition of supersaturated solid solution of Zn in Al) but also the GB transformation, namely the formation of Zn-rich IGFs or complexions in Al/Al GBs.

HPT (5 GPa, 300 K, 5 torsions, 1 rpm) was applied to the Al – 30 wt% Zn polycrystals made of high-purity components. The analytical TEM has been performed with a probe-corrected ARM200F JEOL microscope operated at 200 kV. High Angle Annular Dark Field (HAADF) images were recorded in the scanning mode (STEM) using a probe size of 0.2 nm with a convergence angle of 34 mrad and collection angles in the range of 80–300 mrad. To quantify the local Zn concentrations, energy-dispersive X-ray spectroscopy (EDS) was performed using a JEOL JED2300 detector. Similar to Refs. [87,88], the supersaturated (Al) solid solution almost completely decomposed. The mean Al grain size decreased from 500 μm before deformation to 400 nm after HPT.

The HPT-treated Al–Zn alloys contain some (about 20%) Al/Al GBs with a thin uniform Zn-enriched layer contacting with Zn grains and having non-zero contact angle. Such case is shown in Fig. 4. The contact area of a Zn grain (left bottom corner) and an Al/Al GB (aligned from left bottom to right top) is clearly exhibited (Fig. 4a). The contact (dihedral) angle of the (solid) Zn grain with the Al/Al GB is about 94°.

It is important to underline, that the question of GB wetting becomes far from trivial if the wetting (second) phase is not liquid but solid. Recently, the GB wetting by a second solid phase has been investigated in detail both experimentally [89–93] and theoretically [6,94,95]. Most important difference is that if the wetting phase is solid, the anisotropy of interfacial energies leads to the torque terms in Young equation which cannot be neglected [6,94,95]. However, the long anneals (like in experiments [89–93]) can equilibrate the microstructure, and in this case one can speak about equilibrium GB contact (dihedral) angles. We have to underline, that in case of HPT the microstructure reaches not the equilibrium state (like after long anneals [89–93]) but the steady-state. It is reached in the Al-based alloys after 0.5–1 rotation of anvils and further remains unchanged [87]. One can even speak about so-called equifinal state [96–98]. The equifinal state of an open system is reached in the steady-state and does not depend on the starting state of the system [99]. It is similar to that as equilibrium state of a closed system is reached after long equilibrating annealing and does not depend on the starting state as well.

The respective Al/Al GB clearly appears on the image as a bright line, indicating a local Zn enrichment. This feature was confirmed by the EDS line scan analysis performed across the Al/Al boundary (Fig. 4b). The maximum Zn concentration across the Al/Al boundary is 15 ± 0.5 at%, and large gradients are exhibited (over 4 nm on each side of the interface, also confirmed by the plot of the HAADF signal across the GB in Fig. 4b). Part of this gradient might be attributed to a misalignment of the Al/Al GB under the electron beam. However, one should note that a 2 nm wide plateau is clearly exhibited on the profile, indicating that the Al/Al GB is not wetted completely by a pure Zn layer. Moreover, the thickness of a Zn-rich GB layer is very uniform along all visible GBs. The micrograph obtained with HREM (Fig. 4b) shows the intermediate layer between Al grains with higher magnification. Its thickness is about 2 nm. If one analyses numerous GBs after HPT, one can observe, contrary to the long annealed samples [64], not only Al/Al GBs completely and partially wetted by the solid Zn phase, but also numerous GBs with θ > 0 and thin Zn-enriched layer. The contact angles for these GBs vary between θ = 80 and 160°, and TEM data show that they are not symmetric. The increase of θ from 80 and 160° correlates with thickness decrease of Zn-enriched GB layers from 10 to 2 nm. The PW GBs do not have any visible Zn-enrichment and have contact angles between θ = 120 and 180°.
The Zn-enriched GB layer in Fig. 4b looks structureless (or amorphous), like the GB complexions in sintered oxides [7,10,11,13,14]. However, one has to discuss this feature very cautiously. It might be not the equilibrium but equifinal and, therefore, controlled by HPT process. One needs here more experimental evidence, for example by studying the Al–Zn alloys with various Zn concentrations.

Therefore, the experimental evidence is found in [37] that the pseudopartial wetting exists even in the case when the second (wetting) phase is not liquid but solid. This phenomenon takes place in the Al–Zn system, where the discontinuous GB wetting transition occurs in the (Al)+L two-phase area of the phase diagram and it changes to the continuous one in the (Zn)+L area [67]. The PPW was observed not after conventional annealing and subsequent quenching, but after the HPT in the steady-state stage. The PPW Zn-enriched GB films (complexions) can also explain the unusual superductility of ultra-fine grained Al–Zn alloys after HPT [26,27,48,49].

4. Link between GB complexions and pseudopartial GB wetting

Close to the bulk solidus line the prewetting (premelting) IGFs or complexions exist in GBs. They are observed between GB and bulk solidus lines in the bulk phase diagram. Such IGFs are structurally similar to the thin GB films formed in case of complete GB wetting and deficit of a wetting phase (c.f. Section 2). For example, the prewetting/premelting films have been directly observed by HRTEM for two metallic systems W–Ni and Mo–Ni where the complexions appear to be disordered “quasi-liquid” interfacial films of ~1 nm thick in HRTEM of quenched specimens [100,101]. The IGFs GB and bulk solidus lines lead to the high GB diffusivity [103–105], increased GB mobility [106–108] or GB brittleness [58,102,109]. The first (temperature) derivative of GB energy breaks at the GB solidus line. It means that the formation of prewetting/premelting IGFs or complexions is the phase transition of first order [58]. The measurements on the Cu–Bi samples showed that the electrical conductivity abruptly increased when the network of Bi-rich layers isolating the copper grains one from another had broken [109]. The extreme superplasticity of ultra-fine-grained Al–Zn–Mg alloys (with elongation to failure up to 2500%) in the narrow temperature interval just below the bulk solidus [110–115] is also driven by the formation of liquid-like IGFs or complexions between GB and bulk solidus lines [116,117]. In Al–Zn alloys, the IGFs or complexions between GB and bulk solidus were observed by HREM [116,117], they even give visible input in the melting peak in the calorimetric curves (Fig. 5) [23]. In turn, the calorimetric curves (Fig. 5) permitted us to construct the GB solidus line in the Al–Zn phase diagram (Fig. 6) [23].
The nature of quasi-liquid (or liquid-like) complexions between bulk solidus line and GB solidus line (like those observed in W–Ni [100], Mo–Ni [101], Al–Zn–Mg [110–115], Al–Zn [23,116,117], Fe–Si–Zn [104], Al–Ga [106] and Cu–Bi [102,106,118,119] alloys) is very interesting. On the one hand, simple thermodynamic reasons permit one to expect that the composition of these thin GB layers should correspond to the point at the bulk liquidus line. On the other hand, it is hard to imagine that the layer having thickness of few nm possess the properties close to that of “true” (i.e. bulk) liquid phase. The main experimental problem is that it is hardly possible to investigate the structure of these layers in situ, in other words, at high temperature between bulk solidus line and GB solidus line. Quenching to the room temperature strongly changes the structure of these GB complexions. Similar to the quenching of bulk liquids, the GB complexions in ceramics (like ZnO [120–126] or Si3N4 [10–14]) remain amorphous after cooling and those in metallic alloys (like Cu–Bi [102,106], Ni–Bi [10], W–Ni [100], Mo–Ni [101] or Al–Zn [116]) crystallize. Only kinetic properties of these liquid-like complexions (or controlled by those GB layers) can be measured really in situ, namely at high temperature. The examples are GB diffusivity [103–105,118], GB mobility [106–108], GB brittleness [58,102,109] or superplasticity controlled by the GB sliding [110–115].

If one observes the thin GB layers of a constant thickness (multilayer complexions), it is not easy to distinguish, whether one has the case of (1) prewetting/prewetting in the one-phase area of a bulk phase diagram; (2) thin GB “pancake” due to the deficit of wetting phase or (3) pseudopartial GB wetting by a liquid or solid phase. The big problem is that most frequently the wetting phase (either bulk liquid or second solid phase) can be found only in the TJ “pockets”. The pseudopartial wetting can be clearly identified only if the GB contact (dihedral) angle $\theta \geq 60^\circ$ and the solid/liquid interface is convex (Fig. 7a and b). If the contact angle is low, $\theta \leq 60^\circ$, and the solid/liquid interface is concave (Fig. 7c and d), the difference becomes very tiny. If the solid/liquid interface has a discontinuity (two tangentials) between TJ pocket and GB layer (Fig. 7c), the pseudopartial wetting clearly takes place. If the solid/liquid interface is continuous between TJ pocket and GB layer and one can draw only one tangential (Fig. 7d), then the complete wetting with the deficit of wetting phase takes place.

Thin IGFs (bilayer or multilayer complexions) were experimentally observed also in many other systems [10,11,13,14,20,120–126]. Frequently these cases are quite promising from the point of view of possible pseudopartial wetting. For example, it has been found recently that in Ni–Bi alloys, the average contact (dihedral) angle is $>40^\circ$ (i.e. nonzero) while the GBs are covered continuously by a bilayer interfacial phase (complexion) [20]. Also, the equilibrium-thickness intergranular films that are widely observed in Si3N4 and many other liquid-phase sintered ceramics above the bulk solidus lines also coexist with non-wetting liquid phases (at the sintering temperatures) [11].

The good example is also zinc oxide. ZnO is mainly used for manufacturing of varistors. Varistors exhibit highly non-linear current–voltage characteristics with a high resistivity below a threshold electric field, becoming conductive when this field is exceeded, enabling them to be used in current over-surge protection circuits. The model usually proposed to account for the electrical properties of ZnO-based varistors is constituted on the basis of a bricklayer. ZnO-based varistors are approximated as a stacking of good conducting grains separated by grain boundaries, which support back-to-back double Schottky barriers [120,121]. Polycrystalline zinc oxide contains small amounts of dopants, mainly bismuth oxide. After liquid-phase sintering, such material consists of ZnO grains control the non-linear current-voltage characteristics. The intergranular phase originates from the liquid-phase sintering. The sintering conditions alter the performances of ZnO varistors [120]. An increase in the sintering temperature results usually in a lowering in the nonlinearity of the current–voltage curve. Bhushan et al. pointed out that an increase in the sintering temperature would lower the Schottky barrier height [122] and Wong mentioned that the volatilization of Bi2O3 during the sintering would bring a loss in the non-ohmic property of the varistors [123]. In ZnO–Bi2O3 samples studied in Ref. [124] can be clearly seen that the amorphous Bi-rich thin GB layer has the non-zero contact angle with the Bi2O3 phase in TJ. This situation corresponds to scheme in Fig. 7c and not to that in Fig. 7d. In other words, the pseudopartial GB wetting has been observed in Ref.
Most probably, the pseudopartial GB wetting ZnO–Bi2O3 system is observed not in all GBs and not in all conditions. For example, the TJs in Refs. [125,126] clearly correspond to the scheme of a fine instrument for the so-called grain boundary engineering (term first introduced by Tadao Watanabe [127]). As we saw in this review, the IGFs can improve the magnetic properties (Fe–Nd–B-based hard magnetic alloys, WC–Co cemented carbides and Al-based light alloys). In a classic case, wetting precursors only exist in the one-phase area of a phase diagram (when the wetting phase is unstable in the bulk). On the contrary, the GB complexes connected with pseudopartial GB wetting can be observed in a broader range of phase fields in binary and multicomponent phase diagrams, including two- and multiphase regions, coexisting with the pseudopartial-wetting phases that form non-zero contact (dihedral) contacts where they meet the pseudopartial-wetting complexes. Therefore, such IGFs or GB complexes can be used as a fine instrument for the so-called grain boundary engineering (term first introduced by Tadao Watanabe [127]). As we saw in this review, the IGFs can improve the magnetic properties (Fe–Nd–B-based hard magnetic alloys), fracture toughness and strength (WC–Co cemented carbides) or formability (Al-based light alloys). The experimental search for the IGFs and pseudopartial GB wetting in the technologically important alloys should be based on the (rather cheap) SEM screening of GB wetting in polycrystals combined with (expensive and sophisticated) aberration-corrected HREM studies of individual GBs. Even more complicated (but not less important) should be the experimental investigations of the linear (or tubular) few nm thick enriched layers in the GB triple junctions and in dislocation cores. The wetting conditions for such linear defects are different from those for GBs [128,129], they were expected to serve as channels for the quick formation of GB films [130], and recently they were indeed observed in experiments [4,131].

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